SONY

IMX290LLR

Diagonal 6.46 mm (Type 1/2.8) Approx. 2.13M-Effective Pixel Monochrome CMOS Image Sensor

IMX178LLJ

Diagonal 8.92 mm (Type 1/1.8) Approx. 6.44M-Effective Pixel Monochrome CMOS Image Sensor

IMX226CLJ

Diagonal 9.33 mm (Type 1/1.7) Approx. 12.40M-Effective Pixel Monochrome CMOS Image Sensor

2M, 6M, and 12M Monochrome CMOS Image Sensors for Industrial Applications

Sony Semiconductor Solutions Corporation has commercialized the "IMX290LLR", "IMX178LLJ", and "IMX226CLJ" monochrome back-illuminated CMOS image sensors for industrial camera applications. These image sensors use the STARVISTM technology, which was originally developed for security cameras. 2M-, 6M-, and 12M-pixel image sensors can be selected according to the application. In addition to the basic angle of view, the drive mode can be changed to HD, 5M, and 4K according to the imaging subject. These products also support functions that enable imaging in accordance with the surrounding environment, such as the global reset function and multiple exposure function.

- High sensitivity monochrome image sensors
- 2M-, 6M-, and 12M-pixel lineup
- Global reset function

Exmor R

*Exmor R is a trademark of Sony Corporation. The Exmor R is a Sony's CMOS image sensor with significantly enhanced imaging characteristics including sensitivity and low noise by changing fundamental structure of Exmor™ pixel adopted column parallel A/D converter to back-illuminated type.



*STARVIS is a trademark of Sony Corporation. The STARVIS is back-illuminated pixel technology for CMOS image sensors for surveillance camera applications. It features a sensitivity of 2000 mV or more per 1 µm² (color product, when imaging with a 706 cd/m² light source, F5.6 in 1 s accumulation equivalent), and realizes high picture quality in the visible-light and near infrared light regions.

High sensitivity monochrome image sensors

Products that support monochrome imaging were prepared by making use of the low illumination characteristics of the IMX290LQR^{*1}, IMX178LQJ^{*2}, and IMX226CQJ^{*3} color image sensors, which are equipped with the STARVIS technology that is highly regarded by customers as image sensors for security cameras.

-Diagonal 6.46 mm (Type 1/2.8) Approx. 2.13M-Effectiv Pixel: IMX290LLR -Diagonal 8.92 mm (Type 1/1.8) Approx. 6.44M-Effective Pixel: IMX178LLJ -Diagonal 9.33 mm (Type 1/1.7) Approx. 12.40M-Effective Pixel: IMX226CLJ

The angle of view can be selected according to the application. (Photograph 1, Photograph 2, Photograph 3)

- *1: See the New Product Information released in February 2015. *2: See the New Product Information released in September 2013.
- 2: See the New Product Information released in September 2013
 *3: See the New Product Information released in February 2014.

Multiangle

Various angles of view are available for each sensor in addition to all-pixel output. The IMX290LLR can select all-pixel (Full HD) output or HD output. The IMX178LLJ can select all-pixel 6M output or 5M output with an aspect ratio of

Various functions

The IMX290LLR and IMX178LLJ support multiple exposure drive, and the exposure time can be changed for each frame. The IMX290LLR also supports the DOL (Digital Overlap)-type HDR (High Dynamic Range) function, and can realize multiple exposures with little exposure time difference.

These products are also equipped with the global reset function required by cameras for industrial applications, and 4:3, 5:4, or 16:9 in accordance with the application. The IMX226CLJ can select all-pixel 12M output or 4K output, and is capable of imaging at 60 frame/s in ADC 10-bit mode when 4K output is selected. (Table 3-1, Table 3-2, Table 3-3)

use together with a flash makes it possible to obtain images with low distortion.

The IMX178LLJ and IMX226CLJ use a low-voltage LVDS, and the number of channels used can be reduced according to the frame rate. The IMX290LLR can select from low-voltage LVDS, MIPI CSI-2, or CMOS parallel output interfaces in accordance with the interface to be connected.

<Photograph 1> Condition: 2000 lx F5.6 (Exposure time 17.5 ms, Internal gain 0 dB) <Photograph 2> Condition: 2000 lx F5.6 (Exposure time 25 ms, Internal gain 0 dB)



IMX290LLR

IMX178LLJ

IMX226CLJ

<Photograph 3>

Condition: 2000 lx F5.6

(Exposure time 32 ms, Internal gain 0 dB)

<Table 1 $>$	Device Structure	

Item		IMX290LLR	IMX178LLJ	IMX226CLJ
Output image size		Diagonal 6.46 mm (Type 1/2.8) Full HD Diagonal 4.31 mm (Type 1/4.2) HD	Diagonal 8.92 mm (Type 1/1.8) all-pixel Diagonal 7.83 mm (Type 1/2.0) 4:3 Diagonal 7.92 mm (Type 1/2.0) 5:4 Diagonal 8.51 mm (Type 1/1.9) 16:9	Diagonal 9.33 mm (Type 1/1.7) 12M Diagonal 8.61 mm (Type 1/1.9) 4K
Number of effective pixels		1945 (H) × 1097 (V) 3096 (H) × 2080 (V) approx. 2.13M pixels approx. 6.44M pixels		4072 (H) × 3046 (V) approx. 12.40M pixel 4152 (H) × 2174 (V) approx. 9.03M pixels
Unit ce	ell size	2.9 μm (H) × 2.9 μm (V)	2.4 μm (H) × 2.4 μm (V)	1.85 μm (H) × 1.85 μm (V)
Optional blocks	Horizontal	Front: 0 pixels, rear: 0 pixels	Front: 0 pixels, rear: 0 pixels	Front: 96 pixels, rear: 0 pixels
Optical blacks	Vertical	Front: 10 pixels, rear: 0 pixels	Front: 14 pixels, rear: 0 pixels	Front: 16 pixels, rear: 0 pixels
Input drive	frequency	37.125 MHz / 74.25 MHz	37.125 MHz / 54.0 MHz / 74.25 MHz	72.0 MHz
Output Interface		Low Voltage LVDS 8 ch MIPI (CSI-2) 4Iane CMOS parallel	Low Voltage LVDS 10 ch	Low Voltage LVDS 10 ch
Package		110-pin LGA	128-pin LGA	128-pin LGA
Supply voltage	ge Vod (Typ.)	2.9 V / 1.8 V / 1.2 V	2.9 V / 1.8 V / 1.2 V	2.9 V / 1.8 V / 1.2 V

<Table 2> Image Sensor Characteristics

Item		IMX290LLR	IMX178LLJ	IMX226CLJ	Remarks
Sensitivity (monochrome)	Typ. [F8]	1200 mV	380 mV	250 mV (TBD)	3200 K, 706 cd/m ² 1/30s accumulation
Saturation signal	Min.	914 mV	945 mV	810 mV	Tj = 60 °C

${<}{\mbox{Table 3-1}{>}}$ Basic Drive Mode (IMX290LLR)

Drive mode	Recommended number of recording pixels	Frame rate (Max.) [frame/s]	ADC [bit]
5 11 110	Full HD 1920 (H) × 1080 (V) (1080p) approx. 2.07M pixels	60	12 (Low Voltage LVDS/CSI-2)
		120	10 (Low Voltage LVDS/CSI-2)
(1000p)		30	12/10 (CMOS)
HD	1280 (H) × 720 (V) approx. 0.92M pixels	60	12 (Low Voltage LVDS/CSI-2)
HD (720p)		120	10 (Low Voltage LVDS/CSI-2)
		60	12/10 (CMOS)

<Table 3-2> Basic Drive Mode (IMX178LLJ)

Drive mode	Recommended number of recording pixels	Frame rate (Max.) [frame/s]	ADC [bit]
all-pixel	3072 (H) × 2048 (V)	29.97	14
all-pixer	approx. 6.29M pixels	29.97	12
5M	2592 (H) × 1944 (V)	29.94	14
(4:3)	approx. 5.04M pixels	59.97	12
5M	2560 (H) × 2048 (V)	29.94	14
(5:4)	approx. 5.24M pixels	59.97	12
5M	3072 (H) × 1728 (V)	30	14
(16:9)	(16:9) approx. 5.31M pixels	60	12

<Table 3-3> Basic Drive Mode (IMX226CLJ)

Drive mode	Recommended number of recording pixels	Frame rate (Max.) [frame/s]	ADC [bit]
12M	4000 (H) × 3000 (V)	35	12
(4:3)	approx. 12.00M pixels	40	10
4K	4096 (H) × 2160 (V)	30	12
(17:9)	approx. 8.85M pixels	60	10

*Sony reserves the right to change products and specifications without prior notice.

SONY

IMX226CQJ

Diagonal 9.33 mm (Type 1/1.7) 12.40M-Effective Pixel Color CMOS Image Sensor

Back-illuminated CMOS Image Sensor for Security Cameras and Industrial Applications Supports 4K High Resolution and High Sensitivity

Sony developed approximately 12.40M pixels backilluminated CMOS image sensor, "IMX226CQJ", supporting Type 1/2 and 4K (approximately 17:9 ratio). This image sensor has advantages in both high resolution and high sensitivity with back-illuminated structure 1.85 μ m unit pixel, and suits for next generation of 4K security camera.

- Back-illuminated structure 1.85 µm unit pixel
- Higher resolution 4K video imaging mode (4096 H × 2160 V, 60 frame/s)
- Higher sensitivity and lower noise
- Favorable incident light angle characteristics and F-number dependency

Exmor R

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*STARVIS is a trademark of Sony Corporation. The STARVIS is back-illuminated pixel technology used in CMOS image sensors for surveillance camera applications. It features a sensitivity of 2000 mV or more per 1 µm² (color product, when imaging with a 706 cd/m2 light source, F5.6 in 1 s accumulation equivalent), and realizes high picture quality in the visible-light and near infrared light regions.

Higher Resolution

The IMX226CQJ employs approximately 12.40M effective pixels and supports 12M (4:3 ratio) and 4K (approximately 17:9 ratio). High quality picture and fast video imaging is possible at 4K 60 frame/s with Type 1/1.9 approximately 9.03M pixels (approximately 17:9 ratio), and the specifications serve best for next generation of 4K high resolution security camera.

This image sensor provides higher quality picture and clearer imaging than full HD output image of the existing front-illuminated structure 3.75 μ m unit pixel, the IMX185LQJ*¹. (See photograph 1 and photograph 2.)

*1: See the New Products section released in 2013 August

Higher Sensitivity and Lower Noise

For the image sensor with higher pixel counts supporting 4K video or other formats, the reduced pixel size might cause sensitivity deterioration, which is crucial for security camera purpose.

The IMX226CQJ has back-illuminated structure 1.85 µm unit

pixel and achieves a big difference in its high sensitivity and low noise compared with the existing front-illuminated CMOS image sensor while it keeps 4K and the image size of Type 1/2.

Favorable Incident Light Angle Characteristics and F-number Dependency

The light collecting characteristics were optimized to maximize the light collecting efficiency of the back-illuminated structure. As a result, it obtained better conditions in incident light angle characteristics (See figure 1.) and F-number dependency (See figure 2.) than the existing IMX136LQJ^{*2} with front-illuminated structure 2.8 μ m unit pixel.

These characteristics are extremely important for security

camera which often opens lens diaphragm during night-time shooting. And at the lower F-number better low light performance is possible than front-illuminated structure 2.8 μ m unit pixel, the IMX136LQJ. (See photograph 3.)

Also, optical characteristics of this magnitude mean that the sensor can handle high power zoom lenses.

*2 See the New Products section in CX-NEWS, Volume 68

<Photograph 1> Resolution Comparison (2000 lx, 0 dB)









<Photograph 2> Resolution Comparison (F11, 0 dB)







<Photograph 3> Low Light Sensitivity Comparison (0.68 lx, F0.95, 12 bit, 60 fps, 45 dB)



IMX226CQJ

< Figure 1>Incident Light Angle Characteristics



<Table 1> Device Structure

ltem		IMX226CQJ	
Output image size		Diagonal 9.33 mm (Type 1/1.7) 12M 4:3 ratio Diagonal 8.61 mm (Type 1/1.9) 4K Approx. 17:9 ratio	
Number of effective pixels		4072 (H) × 3046 (V) Approx. 12.40M pixels 4152 (H) × 2174 (V) Approx. 9.03M pixels	
Unit cell size		1.85 μm (H) × 1.85 μm (V)	
Optical blacks		Front: 96 pixels, rear: 0 pixels	
	Vertical	Front: 16 pixels, rear: 0 pixels	
Input drive frequency		72 MHz	
Package		128-pin LGA	
Supply voltage Vod (Typ.)		2.9 V / 1.8 V / 1.2 V	

Sony's existing IMX136LQJ

< Figure 2>F-number Dependency





Item		Value	Remarks
sensitivity (F5.6)	Тур.	280 mV	1/30s accumulation
Saturation signal	Min.	810 mV	Tj = 60 °C

<Table 3> Basic Drive Mode

Drive mode	Number of recommended recording pixels	ADC	Frame rate
12M 4:3 ratio	4000 (H) × 3000 (V) 12.00M pixels		40 frame/s
121VI 4:3 TALIO			35 frame/s
4K Approx.	4096 (H) × 2160 (V)	10 bit	60 frame/s
17:9 ratio	Approx. 8.85M pixels	12 bit	30 frame/s
Full HD	2048 (H) × 1080 (V) Approx. 2.21M pixels	10 bit	60 frame/s